

# isc N-Channel MOSFET Transistor

# **DMNH3010LK3**

## **FEATURES**

- Drain Current –I<sub>D</sub>= 55A@ T<sub>C</sub>=25℃
- · Drain Source Voltage-
- : V<sub>DSS</sub>= 30V(Min)
- Static Drain-Source On-Resistance
- :  $R_{DS(on)} = 9.5 m \Omega$  (Max)
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

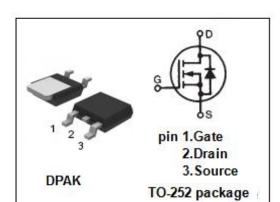
## DESCRIPTION

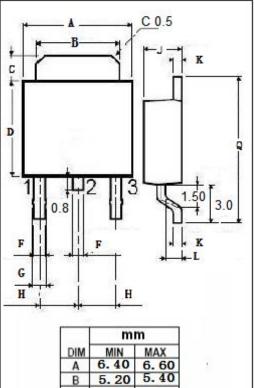
· Designed for use in switch mode power supplies and general purpose applications.

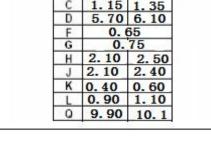
PARAMETER		UNIT	
urce Voltage	30	V	
urce Voltage-Continuous	±20	V	
Drain Current-Continuous		A	
Drain Current-Single Pluse		A	
Total Dissipation @T <sub>C</sub> =25℃		w	
erating Junction Temperatu	ıre -55~175	°C	
Temperature	-55~175	°C	
	urce Voltage urce Voltage-Continuous rrent-Continuous rrent-Single Pluse sipation @Tc=25°C	urce Voltage30urce Voltage-Continuous $\pm 20$ rrent-Continuous55rrent-Single Pluse100sipation @Tc=25°C60erating Junction Temperature-55~175	

### **THERMAL CHARACTERISTICS**

SYMBOL	PARAMETER	МАХ	UNIT
R <sub>th j-c</sub>	Thermal Resistance, Junction to Case	2.5	°C/W







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isc website: www.iscsemi.com

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## **ELECTRICAL CHARACTERISTICS**

#### $T_{\text{C}}\text{=}25\,^\circ\!\!\!\mathrm{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	МАХ	UNIT
V <sub>(BR)DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> = 0; I <sub>D</sub> = 0.25mA	30		V
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> = V <sub>GS</sub> ; I <sub>D</sub> = 0.25mA	1.0	2.5	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> = 10V; I <sub>D</sub> = 18A		9.5	mΩ
lgss	Gate-Body Leakage Current	V <sub>GS</sub> = ±20V;V <sub>DS</sub> = 0		±100	nA
loss	Zero Gate Voltage Drain Current	V <sub>DS</sub> = 30V; V <sub>GS</sub> = 0		1.0	μA
V <sub>SD</sub>	Forward On-Voltage	I <sub>S</sub> = 1.0A; V <sub>GS</sub> = 0		1.0	V

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